



NEC

NEW ENGLAND SEMICONDUCTOR

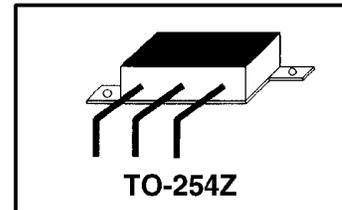
NSG2610

3 AMPERE VOLTAGE REGULATORS

3 TERMINAL
POSITIVE
ADJUSTABLE

- 0.3% Load Regulation
- 0.01% Line Regulation
- Hermetic TO-254Z Pak
- Output Current 3.0A
- Ceramic Feed Throughs

Pinout	
Pin 1	Adjust
Pin 2	V _{out}
Pin 3	V _{in}

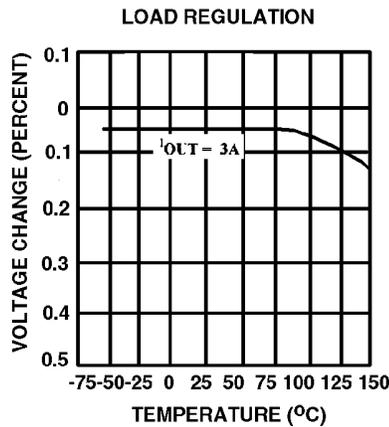
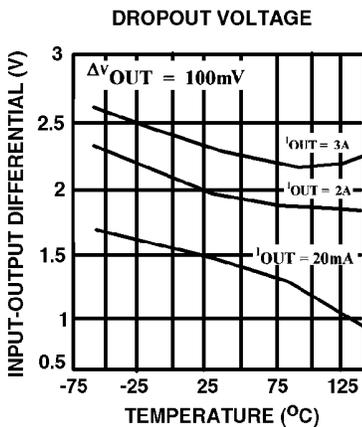
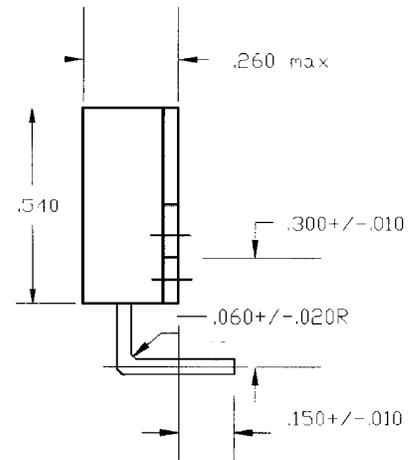
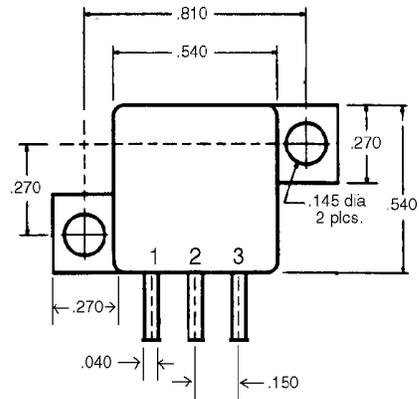


TO-254Z

ABSOLUTE MAXIMUM RATINGS

Power Dissipation.....	Internally limited
Operating Junction Temperature Range.....	- 55°C to + 150°C
Storage Temperature.....	- 65°C to + 150°C
Output Current--	
NSG2610.....	3.0 A
Input Voltage.....	35 V

MECHANICAL OUTLINE



NEW ENGLAND SEMICONDUCTOR

6 Lake Street Lawrence, MA 01841
1-800-446-1158 / (978) 794-1666 / FAX: (978) 689-0803

T4-4.8-860-029 REV: --



NEW ENGLAND SEMICONDUCTOR

NSG2610

Electrical Characteristics ($T_C = 25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Conditions	NSG2610			Units
		Min	Typ	Max	
Line Regulation	$V \leq V_{IN} - V_{OUT} \leq 5V$ $T_j = 25^{\circ}\text{C}$ $15V \leq V_{IN} - V_{OUT} \leq 35V$		0.015	0.2	%
			0.035	0.2	%
			0.05	0.5	%
Load Regulation	$V \leq V_{IN} - V_{OUT} \leq 3V$ $10\text{mA} \leq I_{OUT} \leq I_{FULL\ LOAD}$ $T_j = 25^{\circ}\text{C}$ (1,2)		0.1	0.3	%
			0.2	0.4	%
Thermal Regulation NSG2610	$T_A = 25^{\circ}\text{C}$, 30ms Pulse		0.004	0.02	%W
Adjust Pin Current Change	$10\text{mA} \leq I_{OUT} \leq I_{FULL\ LOAD}$ $1.5V \leq V_{IN} - V_{OUT} \leq 25V$		0.2	5	μA
Adjust Pin Current	$T_j = 25^{\circ}\text{C}$		55		μA
Reference Voltage	$I_{OUT} = 10\text{mA}$, $T_j = 25^{\circ}\text{C}$ $ V_{IN} - V_{OUT} = 3V$ $10\text{mA} \leq I_{OUT} \leq I_{FULL\ LOAD}$ $1.5V \leq V_{IN} - V_{OUT} \leq 25V$	1.238	1.250	1.262	V
		1.225	1.250	1.270	V
Temperature Stability	$-55^{\circ}\text{C} \leq T_j \leq +150^{\circ}\text{C}$		0.5		%
Minimum Load Current	$ V_{IN} - V_{OUT} = 25V$		5	10	mA
Current Limit NSG2610	$ V_{IN} - V_{OUT} = 5V$ $ V_{IN} - V_{OUT} = 25V$	3.2	4.0		A
		0.2	0.5		A
RMS Output Noise (% of V_{OUT})	$T_A = 25^{\circ}\text{C}$, $10\text{Hz} \leq f \leq 10\text{kHz}$		0.003		%
Ripple Rejection	$f = 120\text{Hz}$ $C_{ADJ} = 25\mu\text{F}$, $C_{OUT} = 25\mu\text{F}$ Tantalum $I_{OUT} - I_{FULL\ LOAD}$ $ V_{IN} - V_{OUT} = 3V$	60	75		dB
Long-Term Stability	$T_A = 125^{\circ}\text{C}$, 1000 Hours		0.3	1	%

NOTE 1: Unless otherwise specified, these specifications apply for $V_{in} - V_{out} = 5V$ and $I_{out} = 1.5A$. Power dissipation is guaranteed at these values up to 15 Volts input-output differential. Above 15 Volts input-output differential power dissipation is limited by device internal protection circuitry.

NOTE 2: Regulation is measured at a constant T_j . Changes in output due to heating must be taken into account separately. Pulse testing with low duty cycle is used.

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